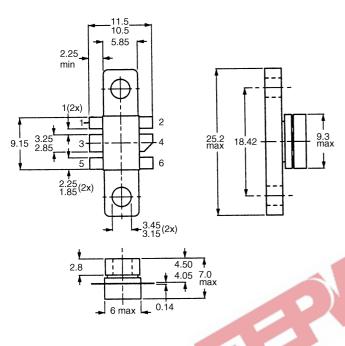


D2293UK

METAL GATE RF SILICON FET

MECHANICAL DATA



SOT 171

PIN 1	SOURCE	PIN 2	SOURCE
PIN 3	GATE	PIN 4	DRAIN
DIN 5	SOURCE	DIN 6	SOURCE

GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET 10W – 12.5V – 500MHz SINGLE ENDED

FEATURES

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- VERY LOW C_{rss}
- SIMPLE BIAS CIRCUITS
- LOW NOISE
- HIGH GAIN 11 dB MINIMUM

APPLICATIONS

 HF/VHF/UHF COMMUNICATIONS from 1 MHz to 1 GHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

P_{D}	Power Dissipation	42W
BV_DSS	Drain – Source Breakdown Voltage	40V
BV_GSS	Gate – Source Breakdown Voltage	±20V
I _{D(sat)}	Drain Current *	8A
T _{stg}	Storage Temperature	−65 to 150°C
T _j	Maximum Operating Junction Temperature	200°C

E-mail: sales@semelab.co.uk Website http://www.semelab.co.uk



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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
B\/	Drain-Source	V _{GS} = 0	I _D = 10mA	40			V
BV _{DSS}	Breakdown Voltage	VGS - 0	ID = IOIIIA	40			\ \ \
1	Zero Gate Voltage	\/ - 12.5\/	V _{GS} = 0			1	mA
IDSS	Drain Current	V _{DS} = 12.5V				ı	IIIA
I _{GSS}	Gate Leakage Current	V _{GS} = 20V	V _{DS} = 0			6	μΑ
V _{GS(th)}	Gate Threshold Voltage *	I _D = 10mA	$V_{DS} = V_{GS}$	1		7	V
9 _{fs}	Forward Transconductance *	V _{DS} = 10V	I _D = 0.6A	0.72			S
G _{PS}	Common Source Power Gain	P _O = 10W		11			dB
η	Drain Efficiency	V _{DS} = 12.5V	$I_{DQ} = 0.4A$	50			%
VSWR	Load Mismatch Tolerance	f = 500MHz	7. 34	20:1			_
C _{iss}	Input Capacitance	$V_{DS} = 0$ V_{GS}		C.		48	pF
C _{oss}	Output Capacitance	V _{DS} = 12.5V V _{GS}	f = 0 $f = 1MHz$			40	pF
C _{rss}	Reverse Transfer Capacitance	$V_{DS} = 12.5V V_{GS}$	g = 0 $f = 1MHz$			4	pF

^{*} Pulse Test: Pulse Duration = 300 μs , Duty Cycle ≤ 2%

HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

THERMAL DATA

R _{THj-case}	Thermal Resistance Junction – Case	Max.4.2°C / W
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Prelim. 7/99